

25. (New) The method of claim 20, wherein the first and third insulating layers are made of silicon oxide and wherein the second and top insulating layers are made of silicon nitride.

REMARKS

Claims 1-8 and 18-25 will be pending upon entry of the present amendment. Claims 9-17 are being canceled in response to the restriction requirement issued by telephone. Claims 18-25 are being newly submitted.

All of the claims remaining in the application are now clearly allowable. Favorable consideration and a Notice of Allowance are earnestly solicited.

Respectfully submitted,

Jérôme Ciavatti

Seed Intellectual Property Law Group PLLC



Robert Iannucci

Registration No. 33,514

RXI:wt

Enclosure:

Postcard

701 Fifth Avenue, Suite 6300
Seattle, Washington 98104-7092
Phone: (206) 622-4900
Fax: (206) 682-6031

318868_1

FAX COPY RECEIVED

SEP 18 2002

TECHNOLOGY CENTER 2800